

RELIABILITY REPORT
FOR
MAX4891ETJ+T

May 24, 2017

PLASTIC ENCAPSULATED DEVICES

MAXIM INTEGRATED

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Conclusion

The MAX4891ETJ+T successfully meets the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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I. Device Description

A. General

The MAX4890/MAX4891/MAX4892 high-speed analog switches meet the needs of 10/100/1000 Base-T applications. These devices switch the signals from two interface transformers and connect the signals to a single 10/100/1000 Base-T Ethernet PHY, simplifying docking station design and reducing manufacturing costs. The MAX4890/MAX4891/MAX4892 can also route signals from a common interface transformer to two different boards in board-redundancy applications. The MAX4890/MAX4891/MAX4892 switches provide an extremely low capacitance and on-resistance to meet Ethernet insertion and return-loss specifications. The MAX4891/MAX4892 feature one and three built-in LED switches, respectively. The MAX4890/MAX4891 are available in space-saving 32- and 36-lead TQFN packages, significantly reducing the required PC board area. These devices operate over the -40°C to +85°C temperature range.



II. Manufacturing Information

A. Description/Function: 10/100/1000 Base-T Ethernet LAN Switch

B. Process: S4C. Fabrication Location: USA

D. Assembly Location: Thailand, TaiwanE. Date of Initial Production: July 23, 2005

III. Packaging Information

A. Package Type: 32-pin TQFN 5x5

B. Lead Frame: Copper

C. Lead Finish: 100% matte Tin

D. Die Attach: Conductive

E. Bondwire: Au (1 mil dia.)

F. Mold Material: Epoxy with silica filler

G. Assembly Diagram: #05-9000-1244H. Flammability Rating: Class UL94-V0

I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C

Level 1

J. Single Layer Theta Ja: 47°C/W
K. Single Layer Theta Jc: 1.7°C/W
L. Multi Layer Theta Ja: 29°C/W
M. Multi Layer Theta Jc: 1.7°C/W

IV. Die Information

A. Dimensions: 61X100 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

C. Interconnect: All with Ti/TiN Barrier

D. Backside Metallization: None

E. Minimum Metal Width: Metal1 = 0.5 / Metal2 = 0.6 / Metal3 = 0.6 microns (as drawn)
 F. Minimum Metal Spacing: Metal1 = 0.45 / Metal2 = 0.5 / Metal3 = 0.6 microns (as drawn)

G. Isolation Dielectric: SiO₂
H. Die Separation Method: Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts: Eric Wright (Reliability Engineering)

Brian Standley (Manager, Reliability) Bryan Preeshl (Vice President of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% for all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppmD. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (a) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 47 \times 2}$$
 (Chi square value for MTTF upper limit)
$$192 \times 4340 \times 47 \times 2$$
 (where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)
$$\lambda = 23.39 \times 10^{-9}$$

$$\lambda = 23.39 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maximintegrated.com/qa/reliability/monitor. Cumulative monitor data for the S4 Process results in a FIT Rate of 0.05 @ 25C and 0.83 @ 55C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing

The AS45 die type has been found to have all pins able to withstand an HBM transient pulse of <500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250mA and overvoltage per JEDEC JESD78.



Table 1Reliability Evaluation Test Results

MAX4891ETJ+T

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS	
Static Life Test (Note 1)						
	Ta = 135C	DC Parameters	47	0		
	Biased	& functionality				
	Time = 192 hrs.					

Note 1: Life Test Data may represent plastic DIP qualification lots.